

## DUAL OPERATIONAL AMPLIFIER

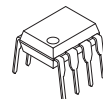
### ■ GENERAL DESCRIPTION

The NJM4560 integrated circuit is a high-gain, wide bandwidth, dual operational amplifier capable of driving 20V peak-to-peak into 400Ω loads. The NJM4560 combines many of the features of the NJM4558 as well as providing the capability of wider bandwidth, and higher slew rate make the NJM4560 ideal for active filters, data and telecommunications, and many instrumentation applications. The availability of the NJM4560 in the surface mounted micro-package allows the NJM4560 to be used in critical applications requiring very high packing densities.

### ■ FEATURES

- Operating Voltage (  $\pm 4V \sim \pm 18V$  )
- Wide Gain Bandwidth Product ( 10MHz typ. )
- Slew Rate (  $4V/\mu s$  typ. )
- Package Outline DIP8, DMP8, SIP8, SOP8 JEDEC 150mil
- Bipolar Technology

### ■ PACKAGE OUTLINE



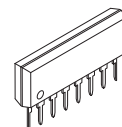
NJM4560D  
( DIP8 )



NJM4560M  
( DMP8 )

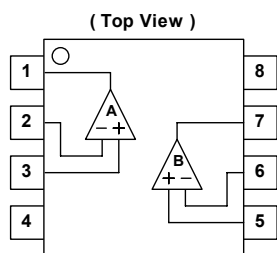


NJM4560E  
( SOP8 )

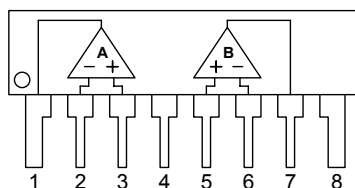


NJM4560L  
( SIP8 )

### ■ PIN CONFIGURATION



NJM4560D, NJM4560M, NJM4560E

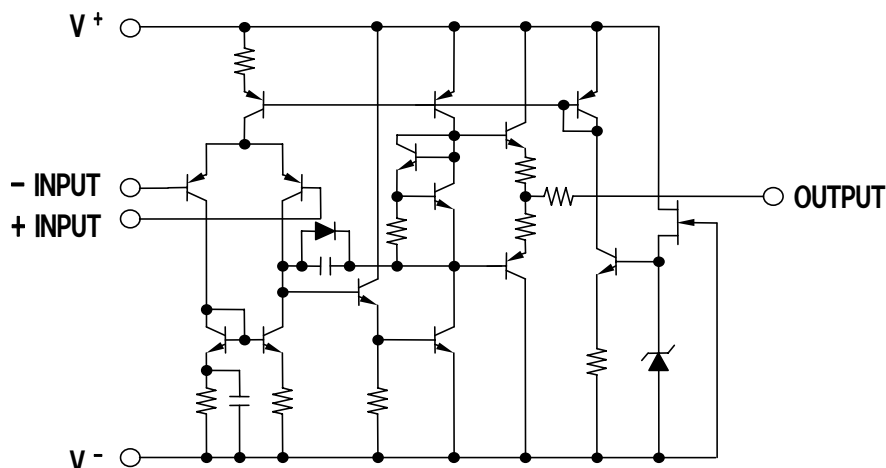


NJM4560L

### PIN FUNCTION

1. A OUTPUT
2. A - INPUT
3. A + INPUT
4.  $V^-$
5. B + INPUT
6. B - INPUT
7. B OUTPUT
8.  $V^+$

### ■ EQUIVALENT CIRCUIT ( 1/2 Shown )



# NJM4560

## ■ ABSOLUTE MAXIMUM RATINGS

( Ta=25°C )

| PARAMETER                   | SYMBOL      | RATINGS                                                      | UNIT |
|-----------------------------|-------------|--------------------------------------------------------------|------|
| Supply Voltage              | $V^+ / V^-$ | $\pm 18$                                                     | V    |
| Differential Input Voltage  | $V_{ID}$    | $\pm 30$                                                     | V    |
| Input Voltage               | $V_{IC}$    | $\pm 15$ ( note )                                            | V    |
| Power Dissipation           | $P_D$       | ( DIP8 ) 500<br>( DMP8 ) 300<br>( SOP8 ) 300<br>( SIP8 ) 800 | mW   |
| Operating Temperature Range | $T_{opr}$   | -40~+85                                                      | °C   |
| Storage Temperature Range   | $T_{stg}$   | -40~+125                                                     | °C   |

( note ) For supply voltage less than  $\pm 15V$ , the absolute maximum input voltage is equal to the supply voltage.

## ■ ELECTRICAL CHARACTERISTICS

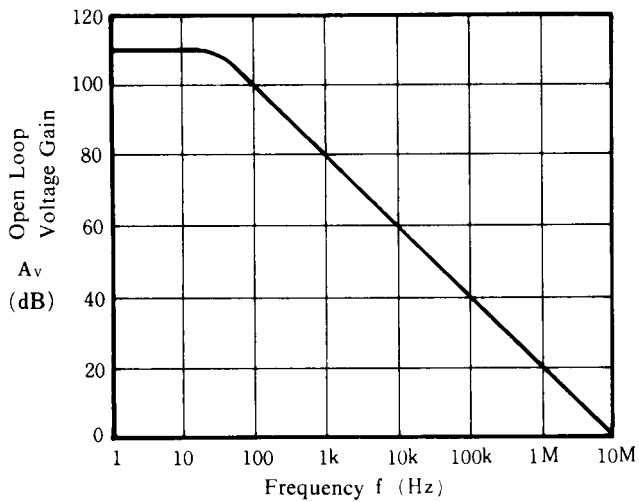
( Ta=25°C,  $V^+ / V^- = \pm 15V$  )

| PARAMETER                       | SYMBOL    | TEST CONDITION                     | MIN.     | TYP.       | MAX. | UNIT  |
|---------------------------------|-----------|------------------------------------|----------|------------|------|-------|
| Input Offset Voltage            | $V_{IO}$  | $R_S \leq 10k\Omega$               | -        | 0.5        | 6    | mV    |
| Input Offset Current            | $I_{IO}$  |                                    | -        | 5          | 200  | nA    |
| Input Bias Current              | $I_B$     |                                    | -        | 40         | 500  | nA    |
| Input Resistance                | $R_{IN}$  |                                    | 0.3      | 5          | -    | MΩ    |
| Large Signal Voltage Gain       | $A_V$     | $R_L \geq 2k\Omega, V_O = \pm 10V$ | 86       | 100        | -    | dB    |
| Maximum Output Voltage Swing 1  | $V_{OM1}$ | $R_L \geq 2k\Omega$                | $\pm 12$ | $\pm 14$   | -    | V     |
| Maximum Output Voltage Swing 2  | $V_{OM2}$ | $I_O = 25mA$                       | $\pm 10$ | $\pm 11.5$ | -    | V     |
| Input Common Mode Voltage Range | $V_{ICM}$ |                                    | $\pm 12$ | $\pm 14$   | -    | V     |
| Common Mode Rejection Ratio     | CMR       | $R_S \leq 10k\Omega$               | 70       | 90         | -    | dB    |
| Supply Voltage Rejection Ratio  | SVR       | $R_S \leq 10k\Omega$               | 76.5     | 90         | -    | dB    |
| Operating Current               | $I_{CC}$  |                                    | -        | 4.3        | 5.7  | mA    |
| Slew Rate                       | SR        |                                    | -        | 4          | -    | V/μs  |
| Gain Bandwidth Product          | GB        |                                    | -        | 10         | -    | MHz   |
| Equivalent Input Noise Voltage  | $V_{NI}$  | RIAA, $R_S = 2k\Omega$ , 30kHz LPF | -        | 1.2        | -    | μVrms |

## ■ TYPICAL CHARACTERISTICS

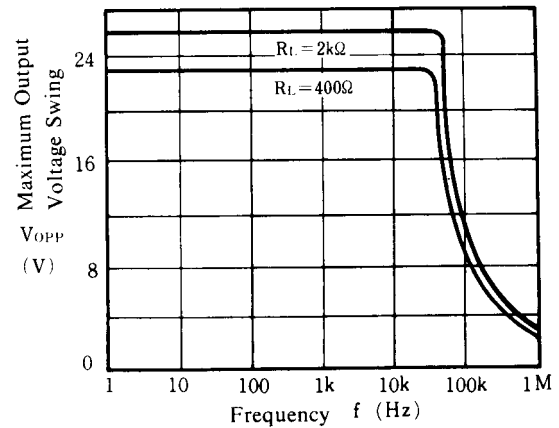
**Open Loop Voltage Gain  
vs. Frequency**

( $V^+/V^- = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $T_a = 25^\circ C$ )



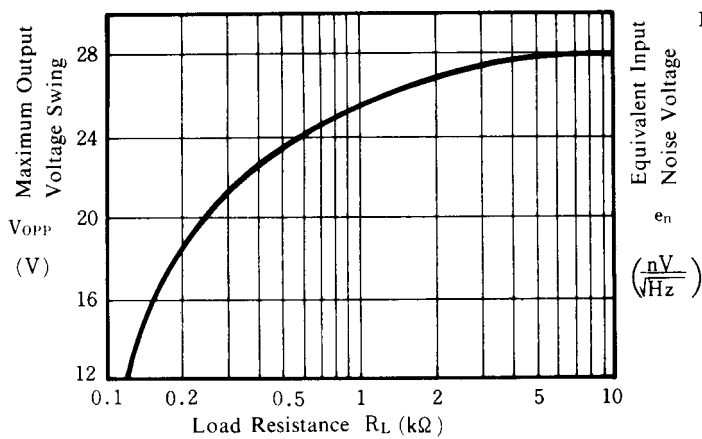
**Maximum Output Voltage Swing  
vs. Frequency**

( $V^+/V^- = \pm 15V$ ,  $T_a = 25^\circ C$ )



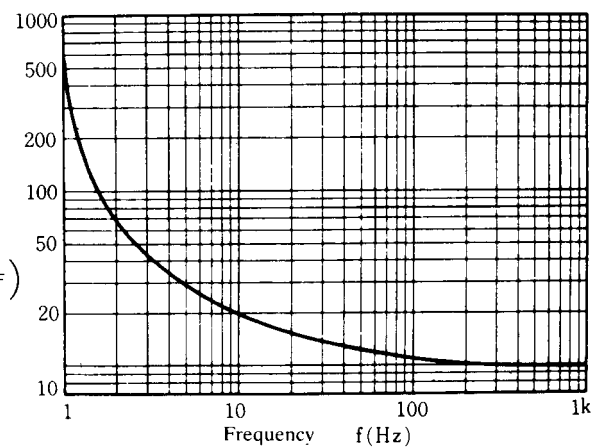
**Maximum Output Voltage Swing  
vs. Load Resistance**

( $V^+/V^- = \pm 15V$ ,  $T_a = 25^\circ C$ )



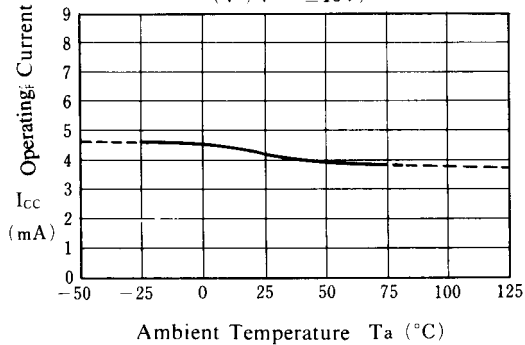
**Equivalent Input Noise Voltage  
vs. Frequency**

( $V^+/V^- = \pm 15V$ ,  $R_s = 50\Omega$ ,  $A_v = 60dB$ ,  $T_a = 25^\circ C$ )



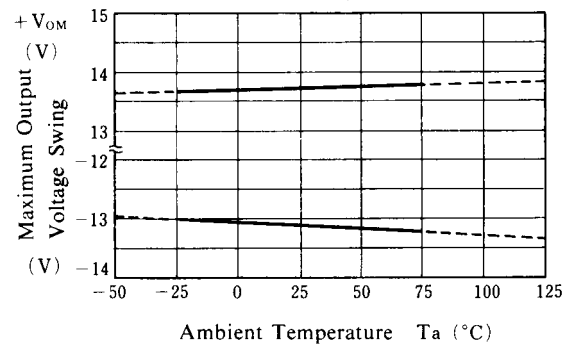
**Operating Current vs. Temperature**

( $V^+/V^- = \pm 15V$ )



**Maximum Output Voltage Swing  
vs. Temperature**

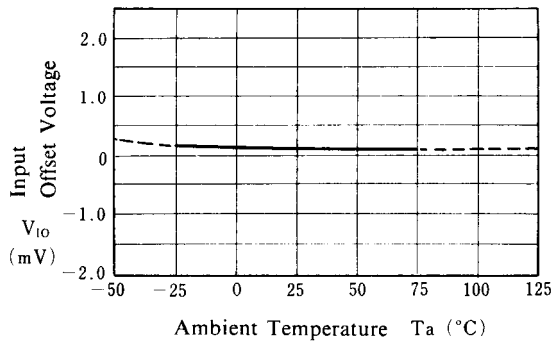
( $V^+/V^- = \pm 15V$ ,  $R_L = 2k\Omega$ )



## ■ TYPICAL CHARACTERISTICS

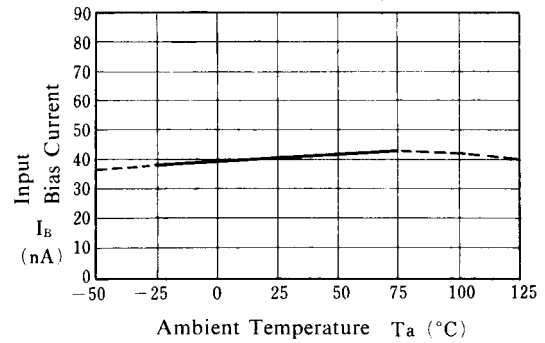
**Input Offset Voltage vs. Temperature**

( $V^+/V^- = \pm 15V$ )



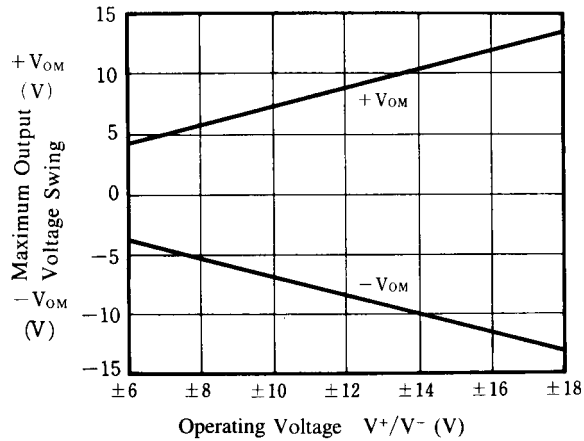
**Input Bias Current vs. Temperature**

( $V^+/V^- = \pm 15V$ )



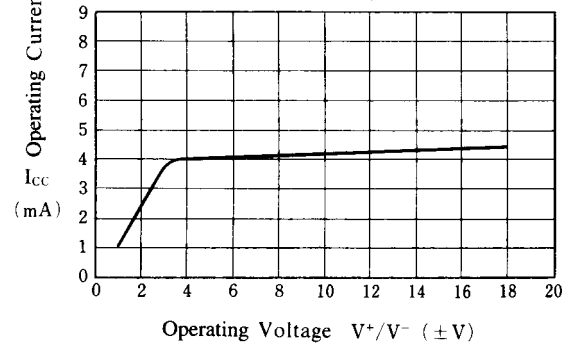
**Maximum Output Voltage Swing vs. Supply Voltage**

( $R_L = 400\Omega$ ,  $T_a = 25^\circ C$ )



**Operating Current vs. Operating Voltage**

( $T_a = 25^\circ C$ )



**[CAUTION]**

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